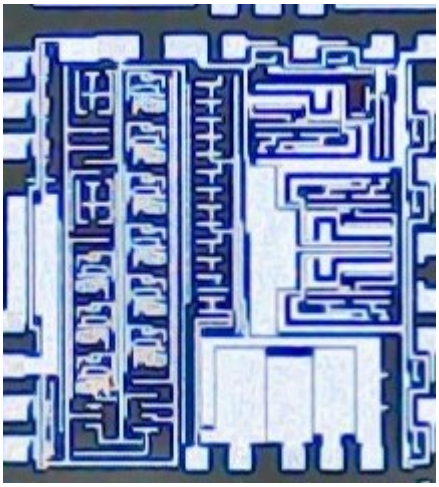
Mixed-signal integrated circuit

A **mixed-signal integrated circuit** is any integrated circuit that has both analog circuits and digital circuits on a single semiconductor die.[1][2][3][4] Their usage has grown dramatically with the increased use of cell phones, telecommunications, portable electronics, and automobiles with electronics and digital sensors.



Mixed signal integrated circuit: the metal areas on the right-hand side are capacitors, on top of which are large output transistors; the left-hand side is occupied by the digital logic

Overview

Integrated circuits (ICs) are generally classified as digital (e.g. a microprocessor) or analog (e.g. an operational amplifier). Mixed-signal ICs contain both digital and analog circuitry on the same chip, and sometimes embedded software. Mixed-signal ICs process both analog and digital signals together. For example, an analog-to-digital converter (ADC) is a typical mixed-signal circuit.

Mixed-signal ICs are often used to convert analog signals to digital signals so that digital devices can process them. For example, mixed-signal ICs are essential components for FM tuners in digital products such as media players, which have digital amplifiers. Any analog signal can be digitized using a very basic ADC, and the smallest and most energy efficient of these are mixed-signal ICs.

Mixed-signal ICs are more difficult to design and manufacture than analog-only or digital-only integrated circuits. For example, an efficient mixed-signal IC may have its digital and analog components share a common power supply. However, analog and digital components have very

different power needs and consumption characteristics, which makes this a non-trivial goal in chip design.

Mixed-signal functionality involves both traditional active elements (like transistors) and well-performing passive elements (like coils, capacitors, and resistors) on the same chip. This requires additional modelling understanding and options from manufacturing technologies. High voltage transistors might be needed in the power management functions on a chip with digital functionality, possibly with a low-power CMOS processor system. Some advanced mixed-signal technologies may enable combining analog sensor elements (like pressure sensors or imaging diodes) on the same chip with an ADC.

Typically, mixed-signal ICs do not necessarily need the fastest digital performance. Instead, they need more mature models of active and passive elements for more accurate simulations and verification, such as for testability planning and reliability estimations. Therefore, mixed-signal circuits are typically realized with larger line widths than the highest speed and densest digital logic, and the implementation technologies can be two to four generations behind the latest digital-only implementation technologies. Additionally, mixed signal processing may need passive elements like resistors, capacitors, and coils, which may require specialized metal, dielectric layers, or similar adaptations of standard fabrication processes. Because of these specific requirements, mixed-signal ICs and digital ICs can have different manufacturers (known as foundries).

Applications

There are numerous applications of mixed-signal integrated circuits, such as in mobile phones, modern radio and telecommunication systems, sensor systems with on-chip standardized digital interfaces (including I2C, UART, SPI, or CAN), voice-related signal processing, aerospace and space electronics, the Internet of things (IoT), unmanned aerial vehicles (UAVs), and automotive and other electrical vehicles. Mixed-signal circuits or systems are typically cost-effective solutions, such as for building modern consumer electronics and in industrial, medical, measurement, and space applications.

Examples of mixed-signal integrated circuits include data converters using delta-sigma modulation, analog-to-digital converters and digital-to-analog converters using error detection and correction, and digital radio chips. Digitally controlled sound chips are also mixed-signal circuits. With the advent of cellular and network technology, this category now includes cellular telephone, software radio, and LAN and WAN router integrated circuits.

Design and development

Typically, mixed-signal chips perform some whole function or sub-function in a larger assembly, such as the radio subsystem of a cell phone, or the read data path and laser SLED control logic of a DVD player. Mixed-signal ICs often contain an entire system-on-a-chip. They may also contain on-chip memory blocks (like OTP), which complicates the manufacturing compared to analog ICs. A mixed-signal IC minimizes off-chip interconnects between digital and analog functionality in the system—typically reducing size and weight due to minimized packaging and a smaller module substrate—and therefore increases the reliability of the system.

Because of the use of both digital signal processing and analog circuitry, mixed-signal ICs are usually designed for a very specific purpose. Their design requires a high level of expertise and careful use of computer aided design (CAD) tools. There also exists specific design tools (like mixed-signal simulators) or description languages (like VHDL-AMS). Automated testing of the finished chips can also be challenging. Teradyne, Keysight, and Advantest are the major suppliers of the test equipment for mixed-signal chips.

There are several particular challenges of mixed-signal circuit manufacturing:

- CMOS technology is usually optimal for digital performance, while bipolar junction transistors are usually optimal for analog performance. However, until the last decade, it was difficult to combine these cost-effectively or to design both in a single technology without serious performance compromises. The advent of technologies like high performance CMOS, BiCMOS, CMOS SOI, and SiGe have removed many of these former compromises.
- Testing functional operation of mixed-signal ICs remains complex, expensive, and often is a "one-off" implementation task (meaning a lot of work is necessary for a product with a single, specific use).
- Systematic design methods of analog and mixed-signal circuits are far more primitive than digital circuits. In general, analog circuit design cannot be automated to nearly the extent that digital circuit design can. Combining the two technologies multiplies this complication.
- Fast-changing digital signals send noise to sensitive analog inputs. One path for this noise is substrate coupling. A variety of techniques are used to attempt to block or cancel this noise coupling, such as fully differential amplifiers,[5] P+ guard-rings,[6] differential topology, on-chip decoupling, and triple-well isolation.[7]

Variations

Mixed-signal devices are available as standard parts, but sometimes custom-designed application-specific integrated circuits (ASICs) are necessary. ASICs are designed for new applications, when new standards emerge, or when new energy source(s) are implemented in the

system. Due to their specialization, ASICs are usually only developed when production volumes are estimated to be high. The availability of ready-and-tested analog- and mixed-signal IP blocks from foundries or dedicated design houses has lowered the gap to realize mixed-signal ASICs.

There also exist mixed-signal field-programmable gate arrays (FPGAs) and microcontrollers.[note 1] In these, the same chip that handles digital logic may contain mixed-signal structures like analog-to-digital and digital-to-analog converter(s), operational amplifiers, or wireless connectivity blocks.[8] These mixed-signal FPGAs and microcontrollers are bridging the gap between standard mixed-signal devices, full-custom ASICs, and embedded software; they offer a solution during product development or when product volume is too low to justify an ASIC. However, they can have performance limitations, such as the resolution of the analog-to-digital converters, the speed of digital-to-analog conversion, or a limited number of inputs and outputs. Nevertheless, they can speed up the system architecture design, prototyping, and even production (at small and medium scales). Their usage also can be supported with development boards, development community, and possibly software support.

History

MOS switched-capacitor circuits

The MOSFET was invented at Bell Labs between 1955 and 1960, after Frosch and Derick discovered and used surface passivation by silicon dioxide to create the first planar transistors, the first in which drain and source were adjacent at the same surface.[9][10][11][12][13] Robert Noyce and Jack Kilby invention of the silicon integrated cicruit was enabled by the planar process developed by Jean Hoerni.[14] In turn, Hoerni's planar process was inspired by the surface passivation method developed at Bell Labs by Carl Frosch and Lincoln Derick in 1955 and 1957.[15][16][17][18][19][20][21]

MOS technology eventually became practical for telephony applications with the MOS mixed-signal integrated circuit, which combines analog and digital signal processing on a single chip, developed by former Bell engineer David A. Hodges with Paul R. Gray at UC Berkeley in the early 1970s.[22] In 1974, Hodges and Gray worked with R.E. Suarez to develop MOS switched capacitor (SC) circuit technology, which they used to develop a digital-to-analog converter (DAC) chip, using MOS capacitors and MOSFET switches for data conversion.[22] MOS analog-to-digital converter (ADC) and DAC chips were commercialized by 1974.[23]

MOS SC circuits led to the development of pulse-code modulation (PCM) codec-filter chips in the late 1970s.[22][24] The silicon-gate CMOS (complementary MOS) PCM codec-filter chip, developed by Hodges and W.C. Black in 1980,[22] has since been the industry standard for digital telephony.[22][24] By the 1990s, telecommunication networks such as the public switched

telephone network (PSTN) had been largely digitized with very-large-scale integration (VLSI) CMOS PCM codec-filters, widely used in electronic switching systems for telephone exchanges, private branch exchanges (PBX), and key telephone systems (KTS); user-end modems; data transmission applications such as digital loop carriers, pair gain multiplexers, telephone loop extenders, integrated services digital network (ISDN) terminals, digital cordless telephones, and digital cell phones; and applications such as speech recognition equipment, voice data storage, voice mail, and digital tapeless answering machines.[24] The bandwidth of digital telecommunication networks has been rapidly increasing at an exponential rate, as observed by Edholm's law,[25] largely driven by the rapid scaling and miniaturization of MOS technology.[26][22]

RF CMOS circuits

While working at Bell Labs in the early 1980s, Pakistani engineer Asad Abidi worked on the development of sub-micron MOSFET (metal–oxide–semiconductor field-effect transistor) VLSI (very large-scale integration) technology at the Advanced LSI Development Lab, along with Marty Lepselter, George E. Smith, and Harry Bol. As one of the few circuit designers at the lab, Abidi demonstrated the potential of sub-micron NMOS integrated circuit technology in high-speed communication circuits, and developed the first MOS amplifiers for Gb/s data rates in optical fiber receivers. Abidi's work was initially met with skepticism from proponents of gallium arsenide and bipolar junction transistors, the dominant technologies for high-speed circuits at the time. In 1985, he joined UCLA, where he pioneered RF CMOS technology in the late 1980s. His work changed the way in which radio-frequency (RF) circuits would be designed, away from discrete bipolar transistors and towards CMOS integrated circuits.[27]

Abidi was researching analog CMOS circuits for signal processing and communications during the late 1980s to early 1990s. In the mid-1990s, the RF CMOS technology that he pioneered was widely adopted in wireless networking, as mobile phones began entering widespread use. As of 2008, the radio transceivers in all wireless networking devices and modern mobile phones are mass-produced as RF CMOS devices.[27]

The baseband processors[28][29] and radio transceivers in all modern wireless networking devices and mobile phones are mass-produced using RF CMOS devices.[27] RF CMOS circuits are widely used to transmit and receive wireless signals in a variety of applications, such as satellite technology (such as GPS), Bluetooth, Wi-Fi, near-field communication (NFC), mobile networks (such as 3G, 4G, and 5G), terrestrial broadcast, and automotive radar applications, among other uses.[30] RF CMOS technology is crucial to modern wireless communications, including wireless networks and mobile communication devices.[31]

Commercial examples

- Examples of mixed-signal design houses and resources:
  - AnSem (http://www.ansem.com)
  - CoreHW (https://www.coreHW.com)
  - EnSilica (https://www.ensilica.com)
  - ICsense (http://www.icsense.com)
  - Presto Engineering (https://www.presto-eng.com/)
  - Sondrel (https://www.sondrel.com/)
  - System to ASIC (http://www.system-to-asic.com)
  - Triad Semiconductor (http://www.triadsemi.com)
- Examples of mixed signal FPGAs and microcontrollers:
  - Analog Devices CM4xx Mixed-Signal Control Processors
  - Fusion FPGA (https://www.microchip.com/en-us/products/fpgas-and-plds/fpgas/fusion-fpgas) (from Microsemi, now part of Microchip Technology)
  - Cypress PSoC – "programmable system on chip", a product from Infineon Technologies (former Cypress Semiconductor)
  - Texas Instruments' MSP430
  - Xilinx mixed signal FPGA (https://www.xilinx.com/publications/prod_mktg/analog-mixed-signal-product-brief.pdf)
- Examples of mixed signal foundries:[note 2]
  - GlobalFoundries
  - New Japan Radio
  - Tower Semiconductor Ltd
  - X-Fab
- List of sound chips
  - Yamaha FM synthesis sound chips
  - POKEY
  - MOS Technology SID

See also

- Analog front-end
- RFIC

Notes

1. Mixed-signal FPGAs are an extension of field-programmable analog arrays.
2. Some foundries may also have design service or list of partners capable for mixed signal design services for their technologies.

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